



PJD50N10AL

100V N-Channel Enhancement Mode MOSFET

Voltage

100 V

Current

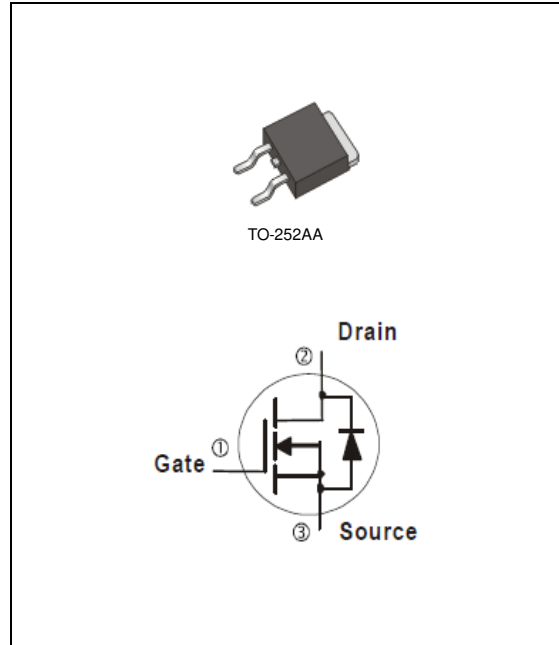
42 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A < 25m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@15A < 28.5m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

- Case : TO-252AA Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0104 ounces, 0.297grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	100	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	$T_C=25^\circ C$	I_D	42	A
	$T_C=100^\circ C$		26	
Pulsed Drain Current (Note 1)	$T_C=25^\circ C$	I_{DM}	150	
Power Dissipation	$T_C=25^\circ C$	P_D	83	W
	$T_C=100^\circ C$		33	
Continuous Drain Current	$T_A=25^\circ C$	I_D	6.3	A
	$T_A=70^\circ C$		5.1	A
Power Dissipation	$T_A=25^\circ C$	P_D	2.0	W
Power Dissipation	$T_A=70^\circ C$		1.3	
Single Pulse Avalanche Energy (Note 6)		E_{AS}	63.4	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	1.5	$^\circ C/W$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	100	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.8	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	20	25	mΩ
		V _{GS} =4.5V, I _D =15A	-	22	28.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic (Note 7)						
Total Gate Charge	Q _g	V _{DS} =50V, I _D =10A, V _{GS} =10V (Note 1,2)	-	29	-	nC
Gate-Source Charge	Q _{gs}		-	4.5	-	
Gate-Drain Charge	Q _{gd}		-	6.4	-	
Input Capacitance	C _{iss}	V _{DS} =30V, V _{GS} =0V, f=1.0MHZ	-	1485	-	pF
Output Capacitance	C _{oss}		-	135	-	
Reverse Transfer Capacitance	C _{rss}		-	67	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =50V, I _D =10A, V _{GS} =10V, R _G =3Ω (Note 1,2)	-	7.8	-	ns
Turn-On Rise Time	t _r		-	30	-	
Turn-Off Delay Time	t _{d(off)}		-	35	-	
Turn-Off Fall Time	t _f		-	14	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	42	A
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V	-	0.7	1.2	V

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T_J(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J = 25°C.
4. The maximum current rating is package limited.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
6. The test condition is L=3mH, I_{AS}=6.5A, V_{DD}=25V, V_{GS}=10V
7. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

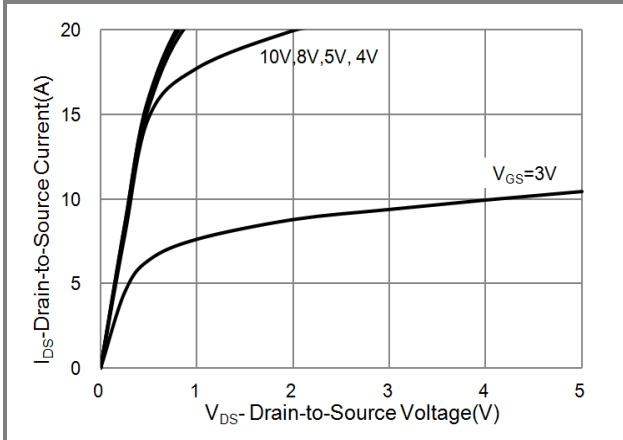


Fig.1 Output Characteristics

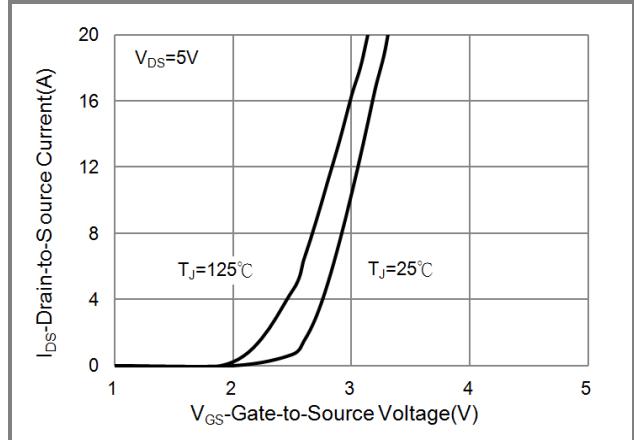


Fig.2 Transfer Characteristics

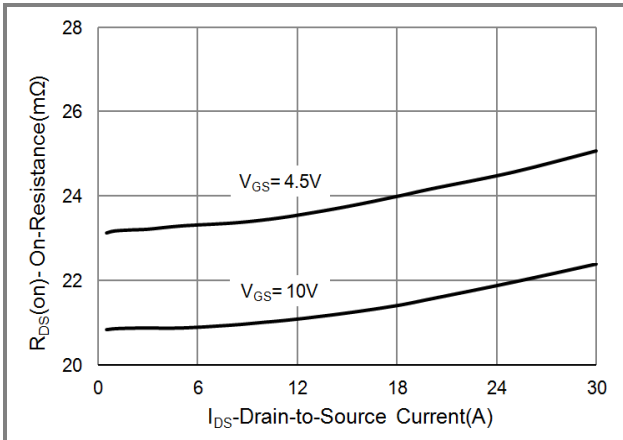


Fig.3 On-Resistance vs. Drain Current

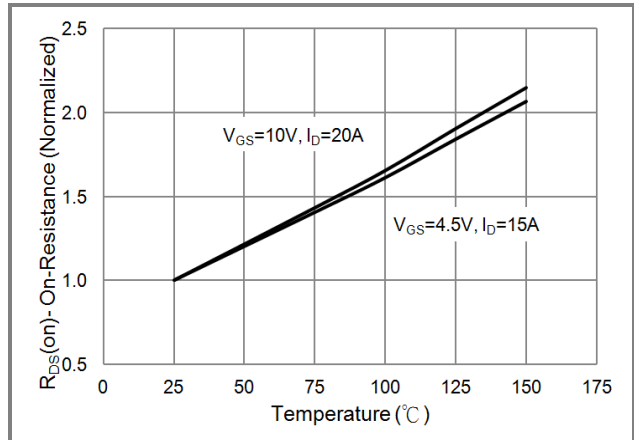


Fig.4 On-Resistance vs. Junction temperature

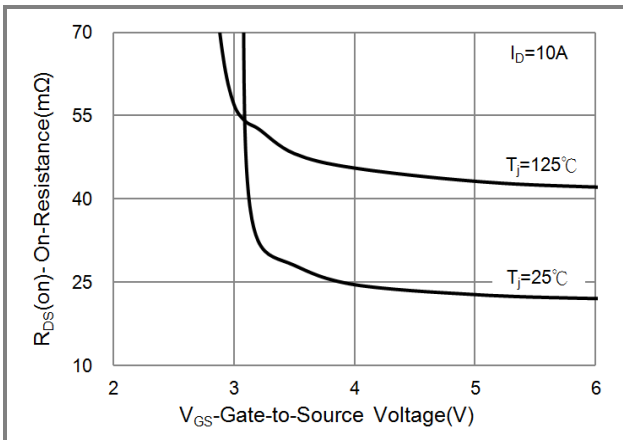


Fig.5 On-Resistance Variation with VGS.

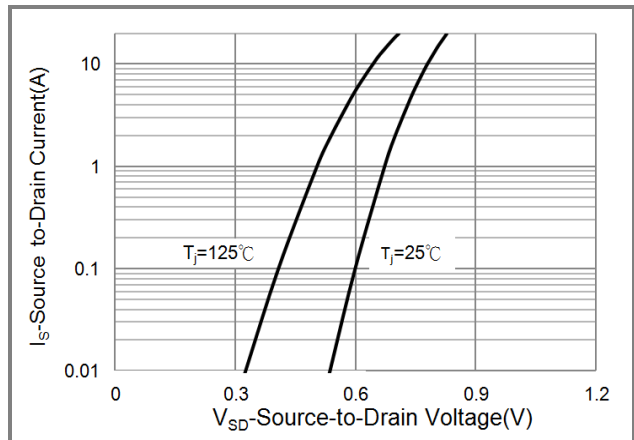


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

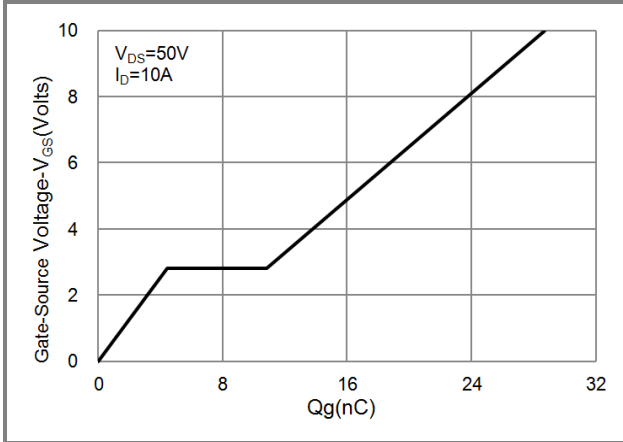


Fig.7 Gate-Charge Characteristics

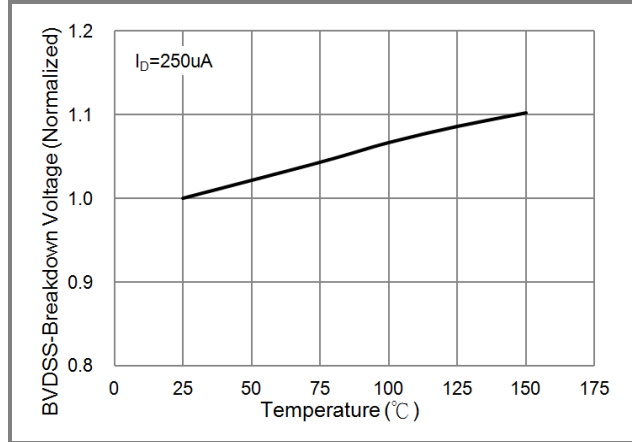


Fig.8 Breakdown Voltage Variation vs. Temperature

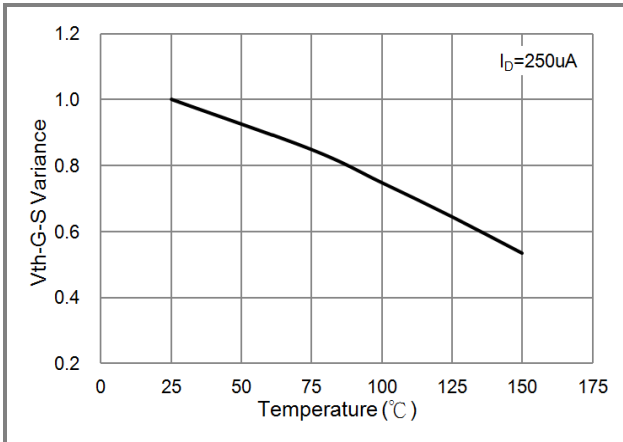


Fig.9 Threshold Voltage Variation with Temperature

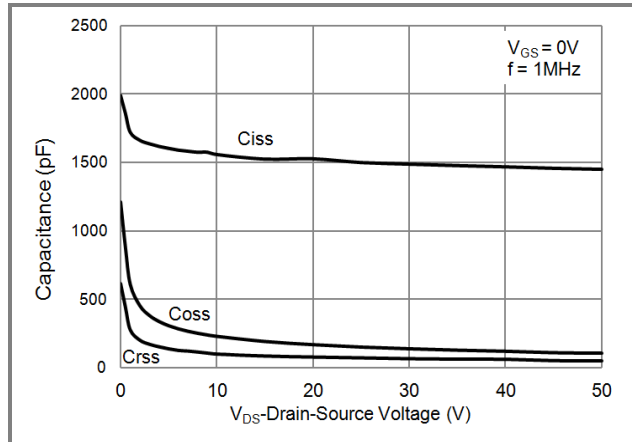


Fig.10 Capacitance vs. Drain-Source Voltage

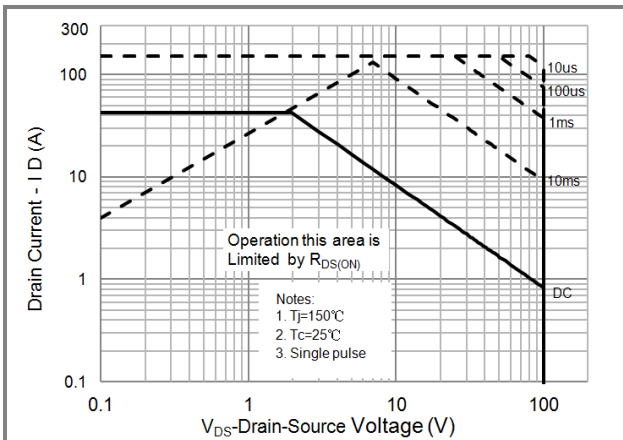
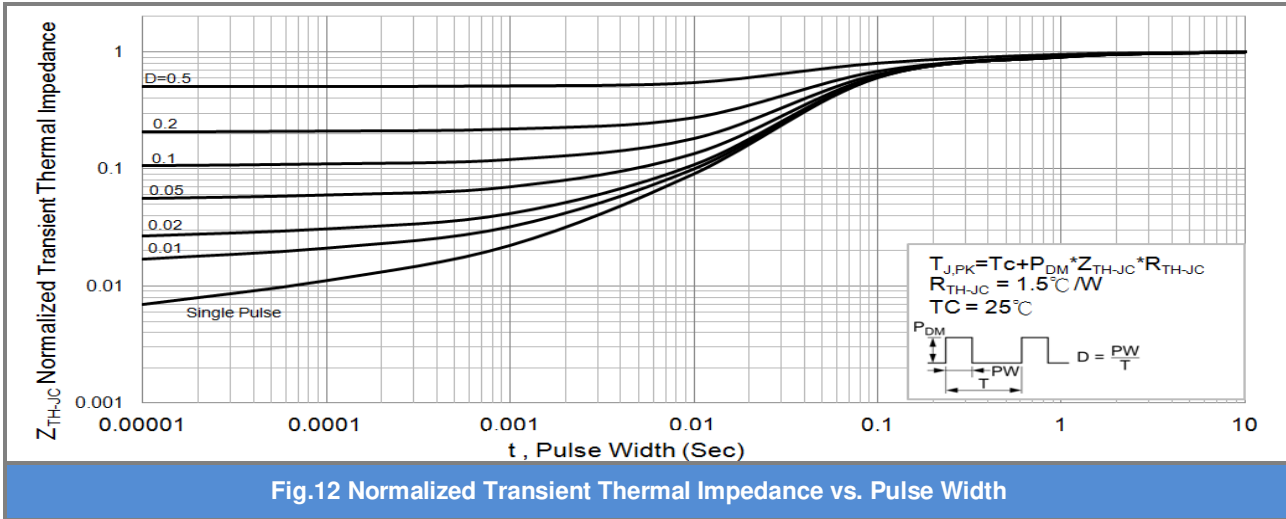


Fig.11 Maximum Safe Operating Area



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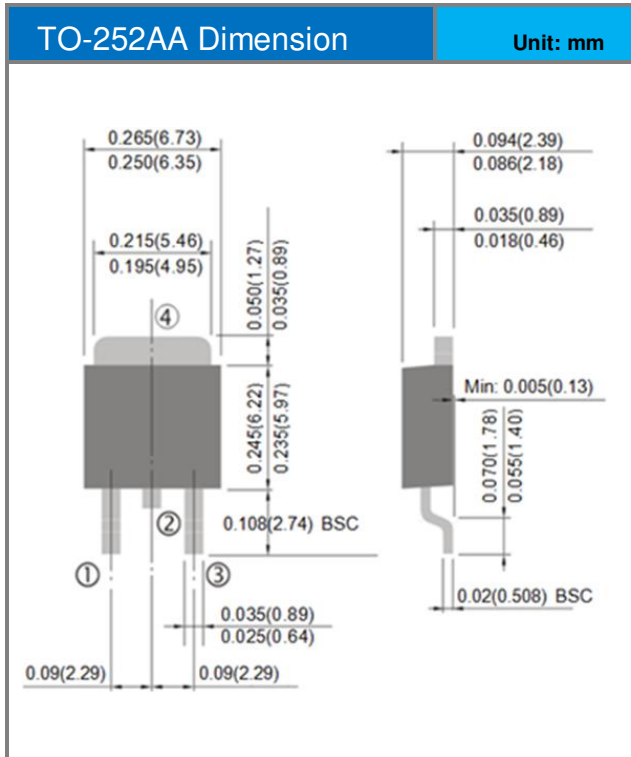
TYPICAL CHARACTERISTIC CURVES





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Packaging Information



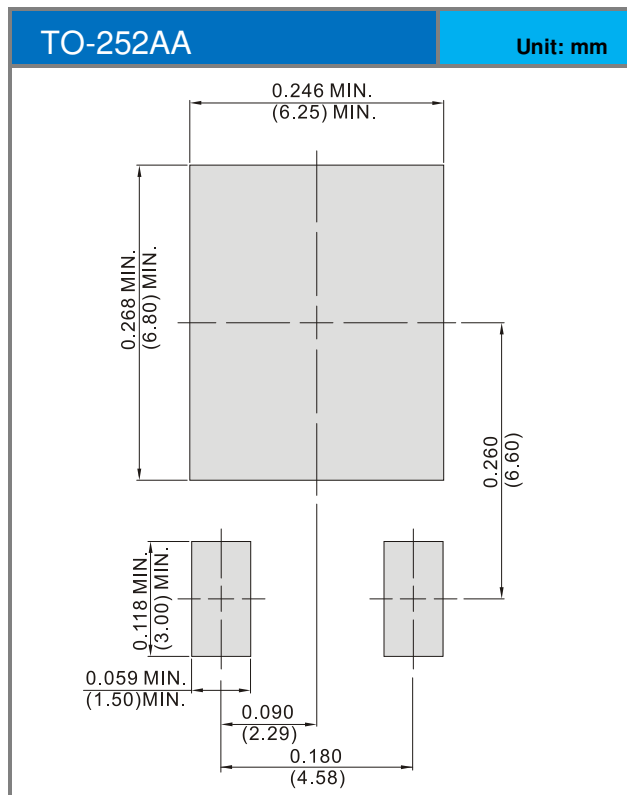


PJD50N10AL

PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD50N10AL_L2_00001	TO-252AA	3,000pcs / 13" reel	50N10AL	Halogen free

MOUNTING PAD LAYOUT





PJD50N10AL

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